

Application Data Sheet

Application Information

Application Type::	Regular
Subject Matter::	Utility
Suggested Group Art Unit::	Not Yet Assigned
CD-ROM or CD-R?::	None
Sequence submission?::	None
Computer Readable Form (CRF)?::	No
Title::	ELECTRODE EMPLOYING NITRIDE- BASED SEMICONDUCTOR OF III-V GROUP COMPOUND, AND PRODUCING METHOD THEREOF
Attorney Docket Number::	245402008300
Request for Early Publication?::	No
Request for Non-Publication?::	No
Total Drawing Sheets::	4
Small Entity?::	No
Petition included?::	No
Secrecy Order in Parent Appl.?::	No

Applicant Information

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Nobuaki
Family Name::	TERAGUCHI
City of Residence::	Oji-cho
Country of Residence::	Japan
Street of mailing address::	2-1-1-304, Katsushimo, Kitakatsuragi-gun
City of mailing address::	Oji-cho
State or Province of mailing address::	Nara

Country of mailing address:: Japan

Correspondence Information

Correspondence Customer Number:: 25226

Representative Information

Representative Customer Number:: 25226

Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-047701	02/25/03	Yes

Assignee Information

Assignee name:: SHARP KABUSHIKI KAISHA
Street of mailing address:: 22-22, Nagaike-cho, Abeno-ku
City of mailing address:: Osaka-shi
State or Province of mailing address:: Osaka
Country of mailing address:: Japan